Advance Information

Analog Multiplexer/ Demultiplexer with Address Latch

High–Performance Silicon–Gate CMOS

MC74VHCT4351

The MC74VHCT4351 utilizes silicon–gate CMOS technology to achieve fast propagation delays, low ON resistances, and low OFF leakage currents. This analog multiplexer/demultiplexer controls analog voltages that may vary across the complete power supply range (from V_{CC} to GND).

The Channel–Select inputs determine which one of the Analog Inputs/ Outputs is to be connected, by means of an analog switch, to the Common Output/Input. The data at the Channel–Select inputs may be latched by using the active–low Latch Enable pin. When Latch Enable is high, the latch is transparent. When either Enable 1 (active low) or Enable 2 (active high) is inactive, all analog switches are turned off.

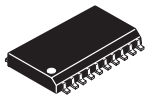
The device input is compatible with TTL–type input thresholds and the output has a full 5V CMOS level output swing. The input protection circuitry on this device allows overvoltage tolerance on the input, allowing the device to be used as a logic–level translator from 3.0V CMOS logic to 5.0V CMOS Logic, or from 1.8V CMOS logic to 3.0V CMOS Logic while operating at the higher–voltage power supply.

The MC74VHCT4351 Enable and Channel Select input structures provide protection when voltages of up to 7V are applied, regardless of the supply voltage. This allows the MC74VHC1T4351 to be used to interface 5V circuits to 3V circuits.

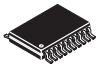
This device has been designed so that the ON resistance (R_{on}) is more linear over input voltage than R_{on} of metal–gate CMOS analog switches.

For multiplexers/demultiplexers without latches, see the VHC4051, VHC4052, and VHC4053.

- Fast Switching and Propagation Speeds
- Low Crosstalk Between Switches
- Diode Protection on All Inputs/Outputs
- Analog Power Supply Range ($V_{CC} – V_{EE}$) = 2.0 to 12 V
- Digital (Control) Power Supply Range (V_{CC} – GND) = 2.0 to 6.0 V
- Improved Linearity and Lower ON Resistance than Metal–Gate Types
- Low Noise
- In Compliance with the Requirements Defined by JEDEC Standard No. 7A



DW SUFFIX
20–LEAD SOIC WIDE PACKAGE
CASE 751D–04

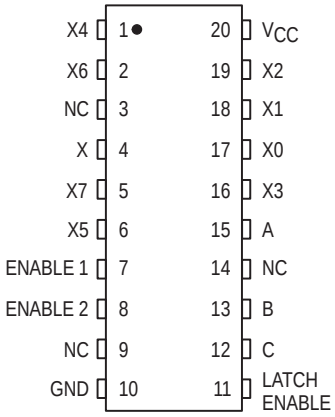


DT SUFFIX
20–LEAD TSSOP PACKAGE
CASE 948E–02

ORDERING INFORMATION

MC74VHCXXXXDW	SOIC Wide
MC74VHCXXXXDT	TSSOP

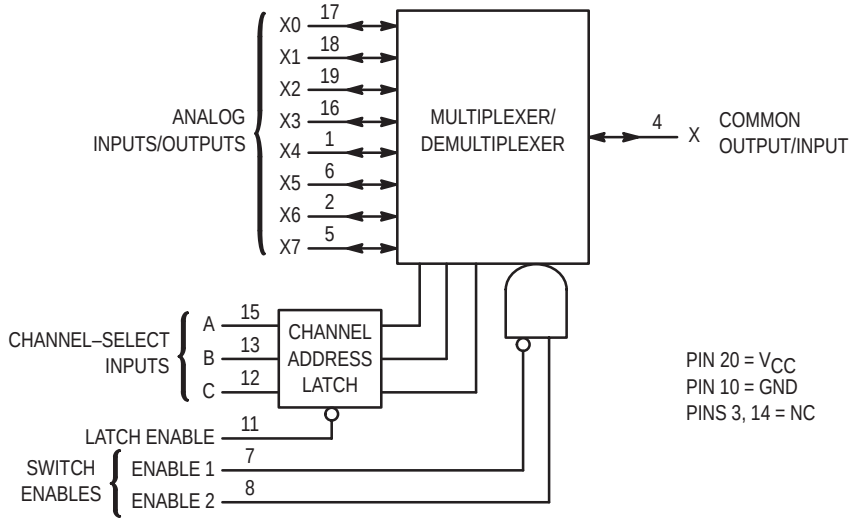
PIN ASSIGNMENT
MC74VHC4351



NC = NO CONNECTION

This document contains information on a new product. Specifications and information herein are subject to change without notice.

LOGIC DIAGRAM
MC74VHC4351
Single–Pole, 8–Position Plus Common Off and Address Latch



FUNCTION TABLE
MC74VHCT4351

Control Inputs					ON Channel (LE = H)*
Enable		Select			
1	2	C	B	A	
L	H	L	L	L	X0
L	H	L	L	H	X1
L	H	L	H	L	X2
L	H	L	H	H	X3
L	H	H	L	L	X4
L	H	H	L	H	X5
L	H	H	H	L	X6
L	H	H	H	H	X7
H	X	X	X	X	None
X	L	X	X	X	None

X = don't care

* When Latch Enable is low, the Channel Selection is latched and the Channel Address Latch does not change states.

MAXIMUM RATINGS*

Symbol	Parameter	Value	Unit
V_{CC}	Positive DC Supply Voltage (Ref. to GND)	– 0.5 to + 7.0	V
V_{IS}	Analog Input Voltage	– 0.5 to V_{CC} + 0.5	V
V_{in}	DC Input Voltage (Ref. to GND)	– 0.5 to V_{CC} + 0.5	V
I	DC Current Into or Out of Any Pin	± 25	mA
P_D	Power Dissipation in Still Air SOIC or TSSOP†	750 500	mW
T_{stg}	Storage Temperature	– 65 to + 150	°C
T_L	Lead Temperature, 1 mm from Case for 10 Seconds	260	°C

* Maximum Ratings are those values beyond which damage to the device may occur. Functional operation should be restricted to the Recommended Operating Conditions.

†Derating — SOIC Package: – 7 mW/°C from 65° to 125°C
TSSOP Package: – 6.1 mW/°C from 65° to 125°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the ranges indicated in the Recommended Operating Conditions.

Unused digital input pins must be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused Analog I/O pins may be left open or terminated. See Applications Information.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Max	Unit
V_{CC}	Positive DC Supply Voltage	(Ref. to GND)	2.0	6.0	V
V_{IS}	Analog Input Voltage		0	V_{CC}	V
V_{in}	Digital Input Voltage (Ref. to GND)		GND	V_{CC}	V
V_{IO}*	Static or Dynamic Voltage Across Switch		—	1.2	V
T_A	Operating Temperature, All Package Types		– 55	+ 125	°C
t_r, t_f	Input Rise and Fall Time, Channel Select or Enable Inputs (Figure 9a)	V_{CC} = 3.0 V ± 0.3 V V_{CC} = 5.0 V ± 0.5 V	0 0	100 20	ns

* For voltage drops across the switch greater than 100 mV (switch on), excessive V_{CC} current may be drawn; i.e., the current out of the switch may contain both V_{CC} and switch input components. The reliability of the device will be unaffected unless the Maximum Ratings are exceeded.

DC ELECTRICAL CHARACTERISTICS Digital Section (Voltages Referenced to GND)

Symbol	Parameter	Test Conditions	V_{CC} V	Guaranteed Limit			Unit
				– 55 to 25°C	≤ 85°C	≤ 125°C	
V_{IH}	Minimum High–Level Input Voltage, Channel–Select or Enable Inputs	R_{on} = Per Spec	3.0 4.5 6.0	1.2 2.0 2.0	1.2 2.0 2.0	1.2 2.0 2.0	V
V_{IL}	Maximum Low–Level Input Voltage, Channel–Select or Enable Inputs	R_{on} = Per Spec	3.0 4.5 6.0	0.53 0.8 0.8	0.53 0.8 0.8	0.53 0.8 0.8	V
I_{in}	Maximum Input Leakage Current, Channel–Select or Enable Inputs	V_{in} = V_{CC} or GND	6.0	± 0.1	± 1.0	± 1.0	μA
I_{CC}	Maximum Quiescent Supply Current (per Package)	Channel Select = V_{CC} or GND Enables = V_{CC} or GND V_{IS} = V_{CC} or GND V_{IO} = 0 V	6.0	4	40	160	μA

DC ELECTRICAL CHARACTERISTICS Analog Section

Symbol	Parameter	Test Conditions	V_{CC} V	Guaranteed Limit			Unit
				– 55 to 25°C	≤ 85°C	≤ 125°C	
R_{on}	Maximum "ON" Resistance	V_{in} = V_{IL} or V_{IH} V_{IS} = V_{CC} to GND I_S ≤ 2.0 mA (Figures 1, 2)	3.0 4.5 6.0	25 18 15	30 23 20	35 28 25	Ω
		V_{in} = V_{IL} or V_{IH} V_{IS} = V_{CC} or GND (Endpoints) I_S ≤ 2.0 mA (Figures 1, 2)	3.0 4.5 6.0	20 15 10	25 20 15	30 25 20	
ΔR_{on}	Maximum Difference in "ON" Resistance Between Any Two Channels in the Same Package	V_{in} = V_{IL} or V_{IH} V_{IS} = 1/2 (V_{CC} – GND) I_S ≤ 2.0 mA	3.0 4.5 6.0	15 8.0 4.0	20 12 7.0	25 15 10	Ω
I_{off}	Maximum Off–Channel Leakage Current, Any One Channel	V_{in} = V_{IL} or V_{IH} V_{IO} = V_{CC} – GND Switch Off (Figure 3)	6.0	0.1	0.5	1.0	μA
	Maximum Off–Channel Leakage Current, Common Channel	V_{in} = V_{IL} or V_{IH} V_{IO} = V_{CC} – GND Switch Off (Figure 4)	6.0	0.2	2.0	4.0	
I_{on}	Maximum On–Channel Leakage Current, Channel to Channel	V_{in} = V_{IL} or V_{IH} Switch to Switch = V_{CC} – GND (Figure 5)	6.0	0.2	2.0	4.0	μA

AC ELECTRICAL CHARACTERISTICS (C_L = 50 pF, Input $t_r = t_f$ = 3 ns)

Symbol	Parameter		V_{CC} V	Guaranteed Limit			Unit
				– 55 to 25°C	≤ 85°C	≤ 125°C	
t_{PLH}, t_{PHL}	Maximum Propagation Delay, Channel–Select to Analog Output (Figure 9)		2.0 3.0 4.5 6.0	30 20 15 15	35 25 18 18	40 30 22 20	ns
t_{PLH}, t_{PHL}	Maximum Propagation Delay, Analog Input to Analog Output (Figure 10)		2.0 3.0 4.5 6.0	4.0 3.0 1.0 1.0	6.0 5.0 2.0 2.0	8.0 6.0 2.0 2.0	ns
t_{PLH}, t_{PHL}	Maximum Propagation Delay, Latch Enable to Analog Output (Figure 12)		2.0 3.0 4.5 6.0	30 20 15 15	35 25 18 18	40 30 22 20	ns
t_{PLZ}, t_{PHZ}	Maximum Propagation Delay, Enable 1 or 2 to Analog Output (Figure 11)		2.0 3.0 4.5 6.0	30 20 15 15	35 25 18 18	40 30 22 20	ns
t_{PZL}, t_{PZH}	Maximum Propagation Delay, Enable 1 or 2 to Analog Output (Figure 11)		2.0 3.0 4.5 6.0	20 12 8.0 8.0	25 14 10 10	30 15 12 12	ns
C_{in}	Maximum Input Capacitance		—	10	10	10	pF
$C_{I/O}$	Maximum Capacitance Analog I/O	Enable 1 = V_{IH}, Enable 2 = V_{IL}	—	35	35	35	pF
	Common O/I		—	130	130	130	
	Feedthrough		—	1.0	1.0	1.0	

C_{PD}	Power Dissipation Capacitance (Per Package) (Figure 13.)*	**Typical @ 25°C, V_{CC} = 5.0 V**	pF
		45	

* Used to determine the no–load dynamic power consumption: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

TIMING REQUIREMENTS (Input $t_r = t_f = 3$ ns)

Symbol	Parameter	V_{CC} V	Guaranteed Limit			Unit
			– 55 to 25°C	≤ 85°C	≤ 125°C	
t_{su}	Minimum Setup Time, Channel–Select to Latch Enable (Figure 12)	2.0 3.0 4.5 6.0	50 25 15 10	75 35 20 15	100 45 25 20	ns
t_h	Minimum Hold Time, Latch Enable to Channel Select (Figure 12)	2.0 3.0 4.5 6.0	0 0 0 0	0 0 0 0	0 0 0 0	ns
t_w	Minimum Pulse Width, Latch Enable (Figure 12)	2.0 3.0 4.5 6.0	30 18 12 10	40 23 15 12	50 30 18 15	ns
t_r, t_f	Maximum Input Rise and Fall Times, Channel–Select, Latch Enable, and Enables 1 and 2	2.0 3.0 4.5 6.0	500 300 90 90	500 300 90 90	500 300 90 90	ns

ADDITIONAL APPLICATION CHARACTERISTICS (GND = 0.0 V)

Symbol	Parameter	Test Condition	V_{CC} V	Limit* 25°C 74VHCT	Unit
BW	Maximum On–Channel Bandwidth or Minimum Frequency Response (Figure 6)	f_{in} = 1 MHz Sine Wave Adjust f_{in} Voltage to Obtain 0 dBm at V_{OS} Increase f_{in} Frequency Until dB Meter Reads – 3 dB R_L = 50 Ω, C_L = 10 pF	 3.0 4.50 6.00	 80 80 80	MHz
—	Off–Channel Feedthrough Isolation (Figure 7)	f_{in} ≡ Sine Wave Adjust f_{in} Voltage to Obtain 0 dBm at V_{IS} f_{in} = 10 kHz, R_L = 600 Ω, C_L = 50 pF f_{in} = 1.0 MHz, R_L = 50 Ω, C_L = 10 pF	 3.0 4.50 6.00 3.0 4.50 6.00	 – 50 – 50 – 50 – 40 – 40 – 40	dB
—	Feedthrough Noise, Channel Select Input to Common O/I (Figure 8)	V_{in} ≤ 1 MHz Square Wave ($t_r = t_f$ = 3 ns) Adjust R_L at Setup so that I_S = 0 A Enable = GND R_L = 600 Ω, C_L = 50 pF R_L = 10 kΩ, C_L = 10 pF	 3.0 4.50 6.00 3.0 4.50 6.00	 25 105 135 35 145 190	mV_{PP}
THD	Total Harmonic Distortion (Figure 14)	f_{in} = 1 kHz, R_L = 10 kΩ, C_L = 50 pF $THD = THD_{Measured} - THD_{Source}$ V_{IS} = 2.0 V_{PP} sine wave V_{IS} = 4.0 V_{PP} sine wave V_{IS} = 5.5 V_{PP} sine wave	 3.0 4.50 6.00	 0.10 0.08 0.05	%

* Limits not tested. Determined by design and verified by qualification.

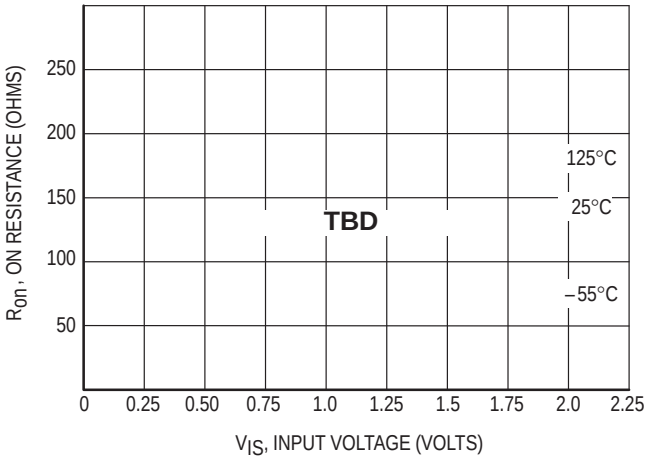


Figure 1a. Typical On Resistance, V_{CC} = 2.0 V

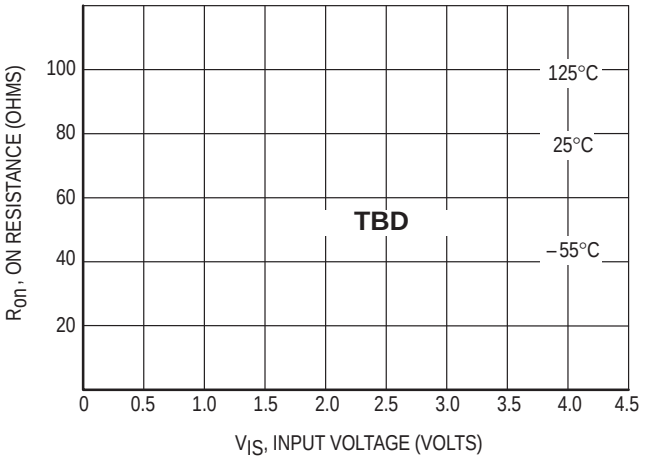


Figure 1b. Typical On Resistance, V_{CC} = 3.0 V

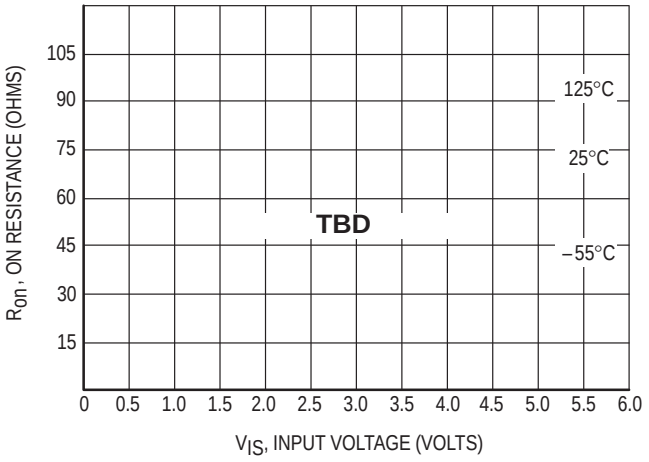


Figure 1c. Typical On Resistance, V_{CC} = 4.5 V

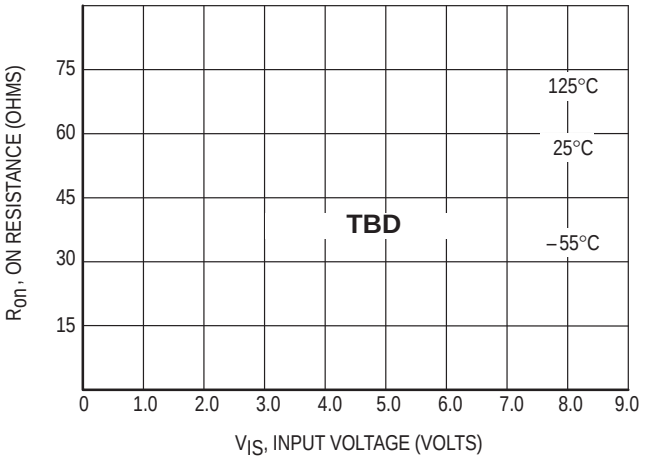


Figure 1d. Typical On Resistance, V_{CC} = 6.0 V

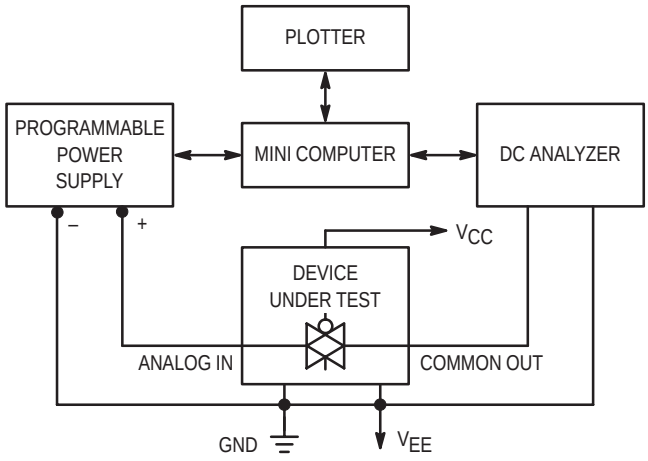


Figure 2. On Resistance Test Set–Up

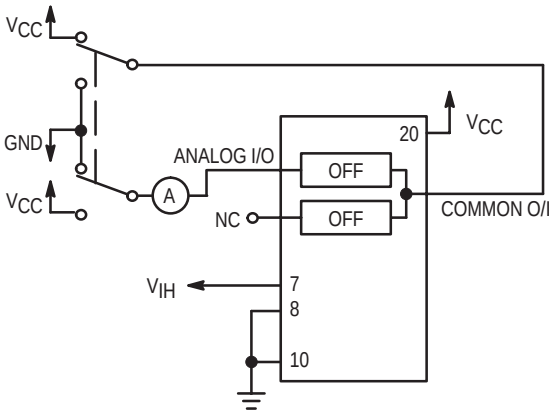


Figure 3. Maximum Off Channel Leakage Current, Any One Channel, Test Set–Up

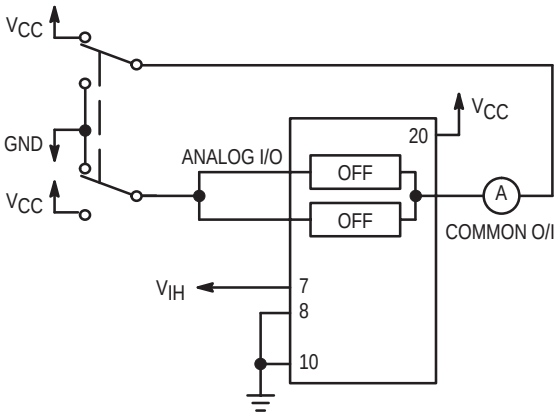


Figure 4. Maximum Off Channel Leakage Current, Common Channel, Test Set–Up

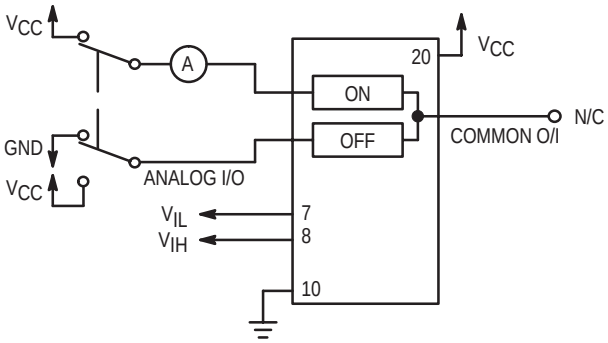
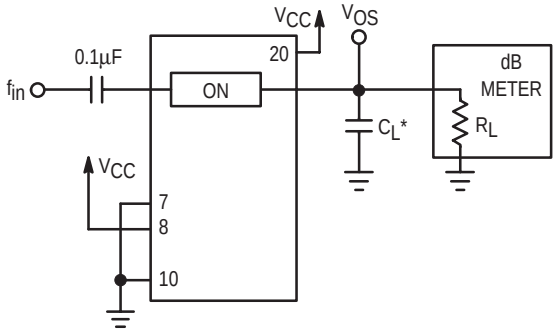
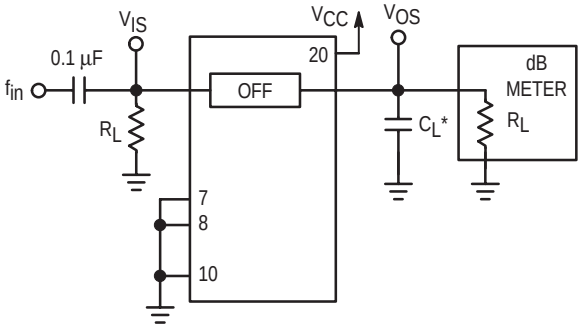


Figure 5. Maximum On Channel Leakage Current, Channel to Channel, Test Set–Up



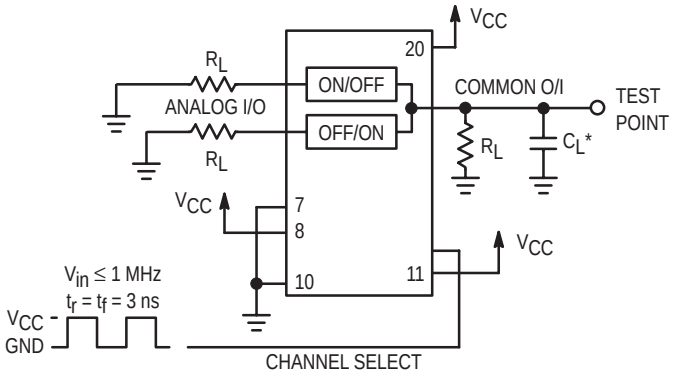
*Includes all probe and jig capacitance.

Figure 6. Maximum On Channel Bandwidth, Test Set–Up



*Includes all probe and jig capacitance.

Figure 7. Off Channel Feedthrough Isolation, Test Set–Up



*Includes all probe and jig capacitance.

Figure 8. Feedthrough Noise, Channel Select to Common Out, Test Set–Up

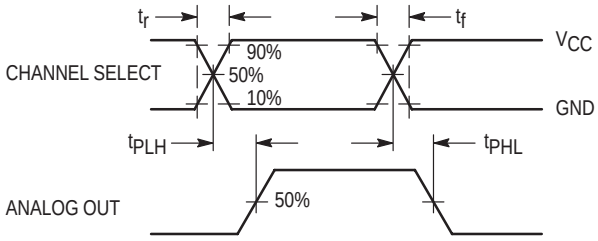


Figure 9a. Propagation Delays, Channel Select to Analog Out

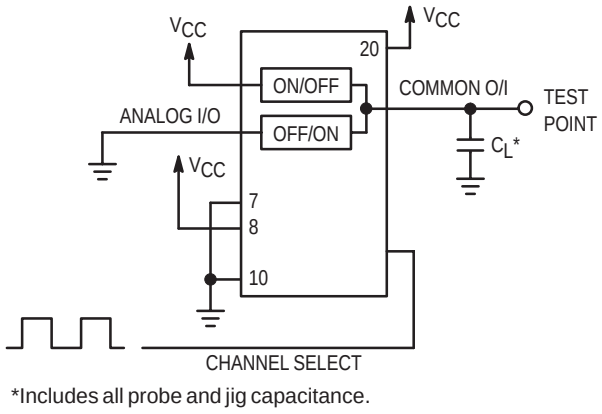


Figure 9b. Propagation Delay, Test Set–Up Channel Select to Analog Out

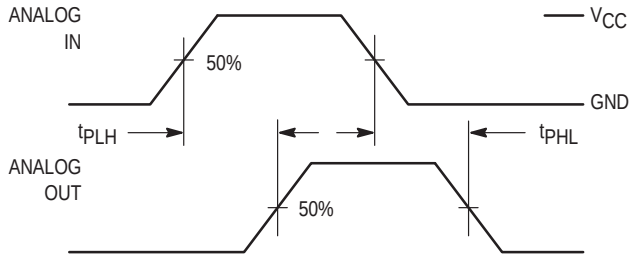


Figure 10a. Propagation Delays, Analog In to Analog Out

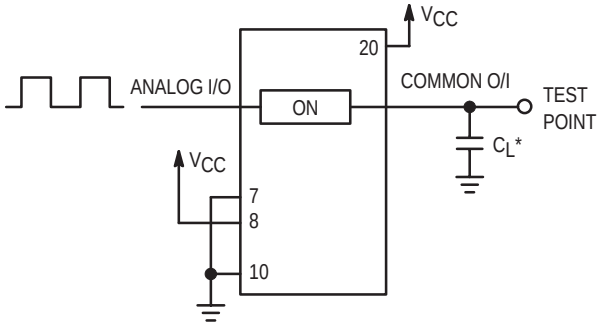


Figure 10b. Propagation Delay, Test Set–Up Analog In to Analog Out

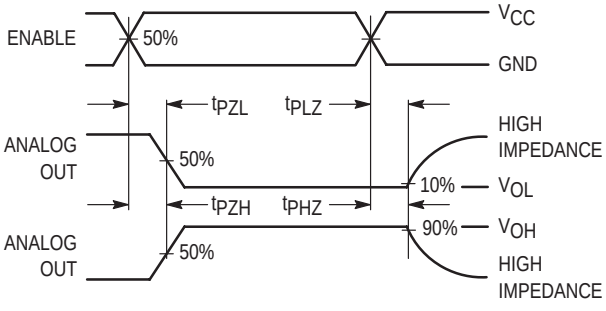


Figure 11a. Propagation Delay, Enable 1 or 2 to Analog Out

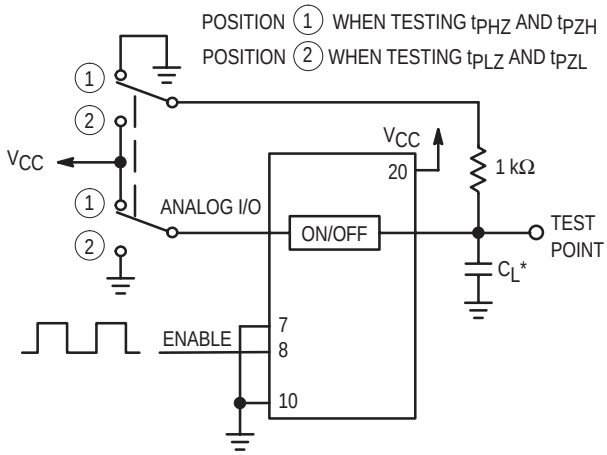


Figure 11b. Propagation Delay, Test Set–Up Enable to Analog Out

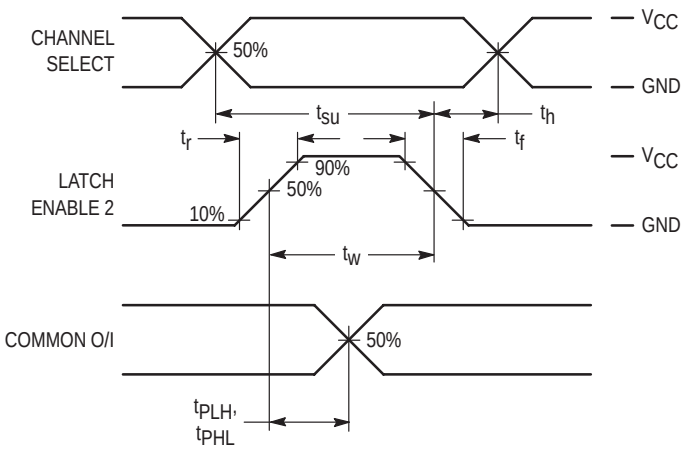
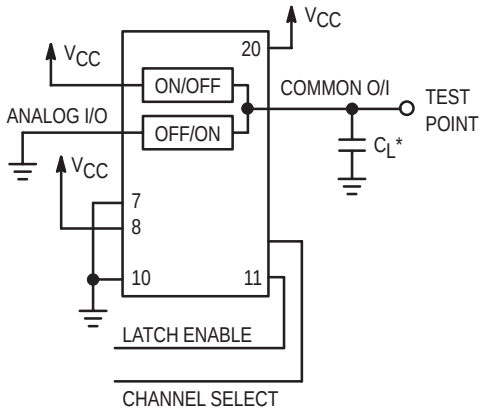


Figure 12a. Propagation Delay, Latch Enable to Analog Out



*Includes all probe and jig capacitance.

Figure 12b. Propagation Delay, Test Set–Up Latch Enable to Analog Out

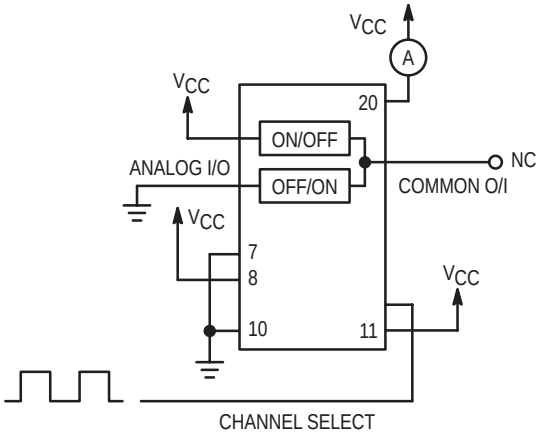
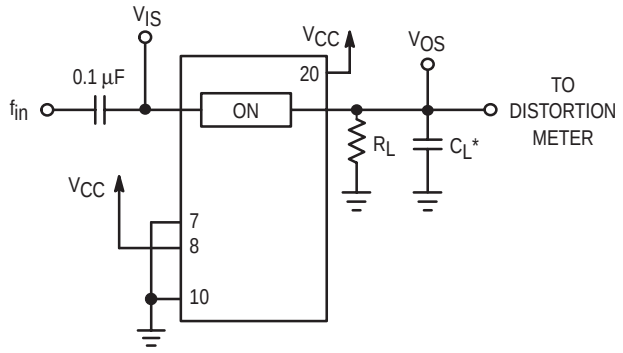


Figure 13. Power Dissipation Capacitance, Test Set-Up



*Includes all probe and jig capacitance.

Figure 14a. Total Harmonic Distortion, Test Set-Up

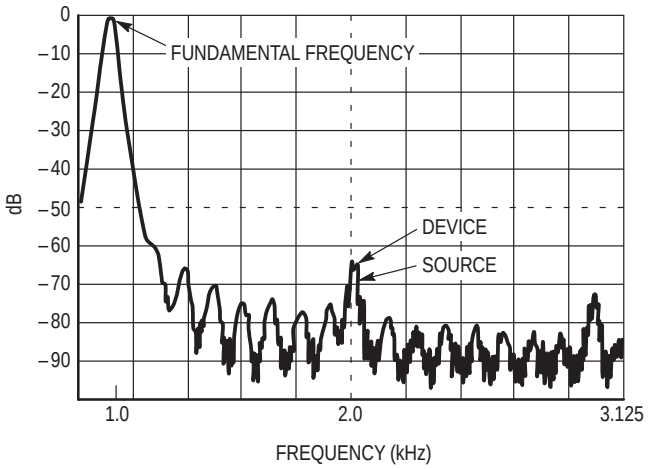


Figure 14b. Plot, Harmonic Distortion

APPLICATIONS INFORMATION

The Channel Select and Enable control pins should be at V_{CC} or GND logic levels. V_{CC} being recognized as a logic high and GND being recognized as a logic low. In this example:

V_{CC} = + 5 V = logic high

GND = 0 V = logic low

The maximum analog voltage swings are determined by the supply voltages V_{CC} and GND. The positive peak analog voltage should not exceed V_{CC}. Similarly, the negative peak analog voltage should not go below GND. In this example, the difference between V_{CC} and GND is five volts. Therefore, using the configuration in Figure 15, a maximum analog signal of five volts peak–to–peak can be controlled. Unused analog inputs/outputs may be left floating (i.e., not connected). However, tying unused analog inputs and outputs to V_{CC} or GND through a low value resistor helps minimize crosstalk and feedthrough noise that may be picked up by an unused switch.

Although used here, balanced supplies are not a requirement. The only constraints on the power supplies are that:

V_{CC} – GND = 2 to 6 volts

When voltage transients above V_{CC} and/or below GND are anticipated on the analog channels, external Germanium or Schottky diodes (D_X) are recommended as shown in Figure 16. These diodes should be able to absorb the maximum anticipated current surges during clipping.

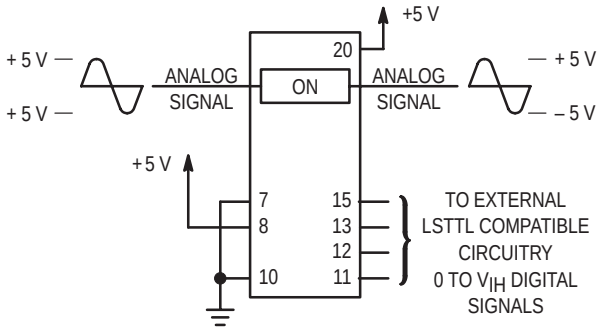


Figure 15. Application Example

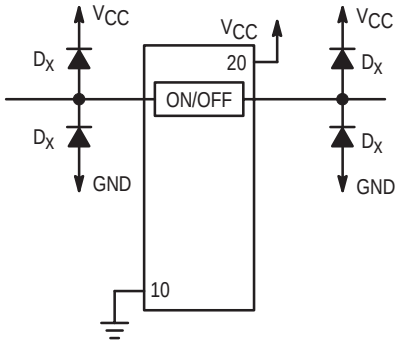
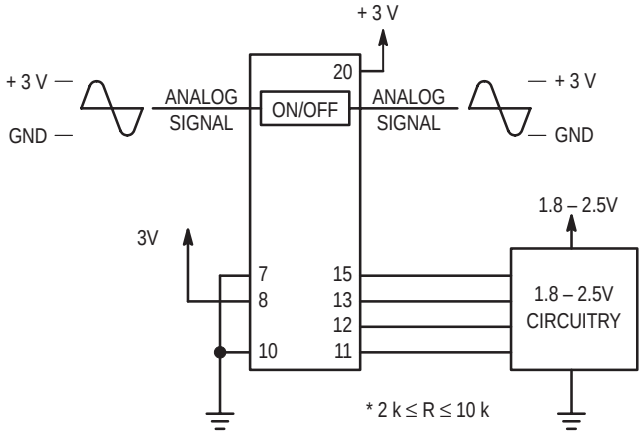
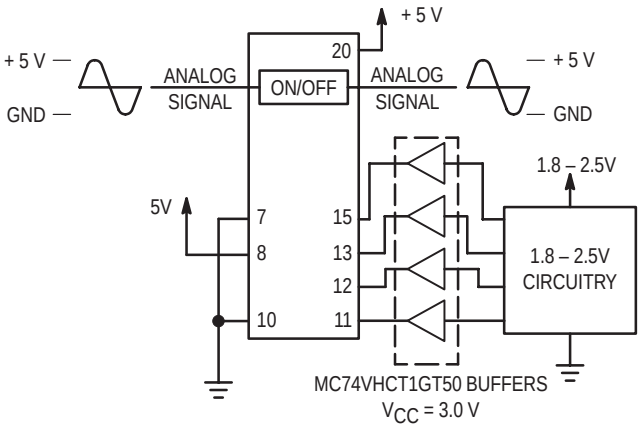


Figure 16. External Germanium or Schottky Clipping Diodes



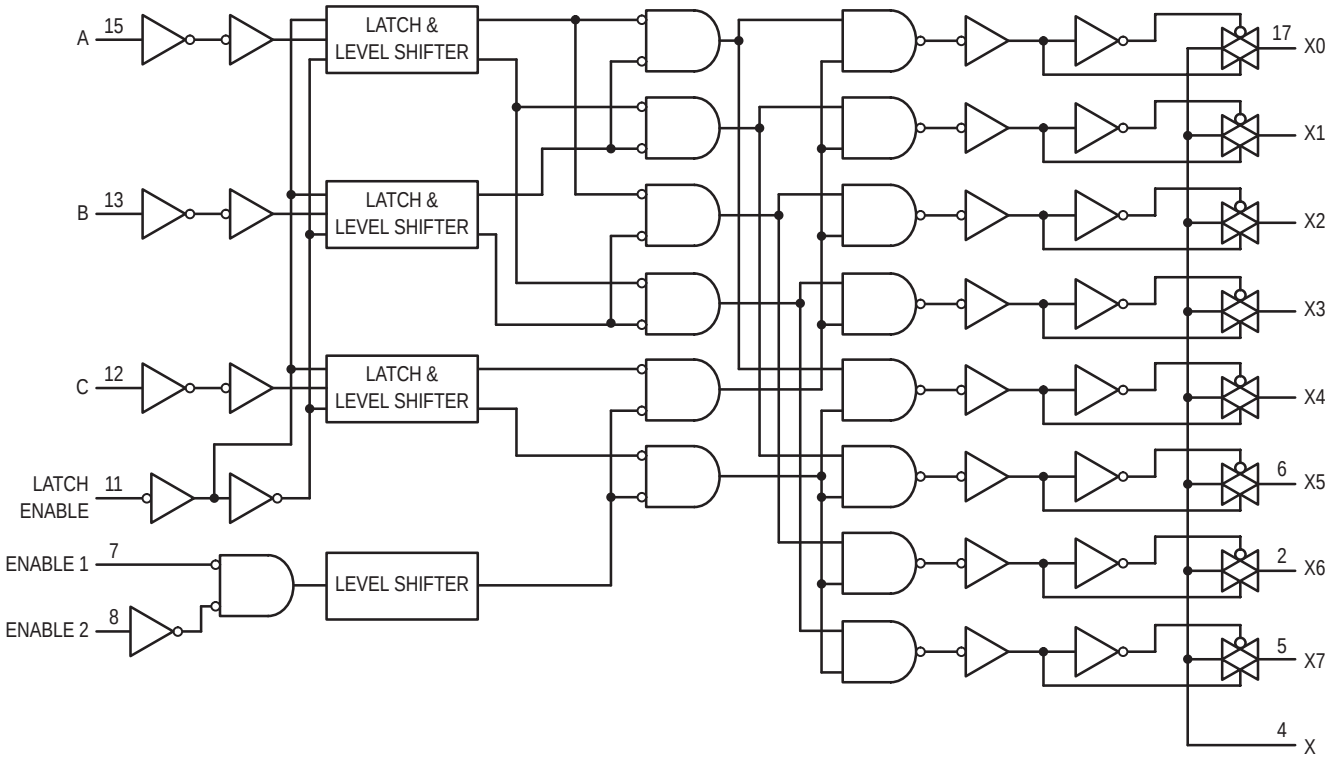
a. Low Voltage Logic Level Shifting Control



b. 2–Stage Logic Level Shifting Control

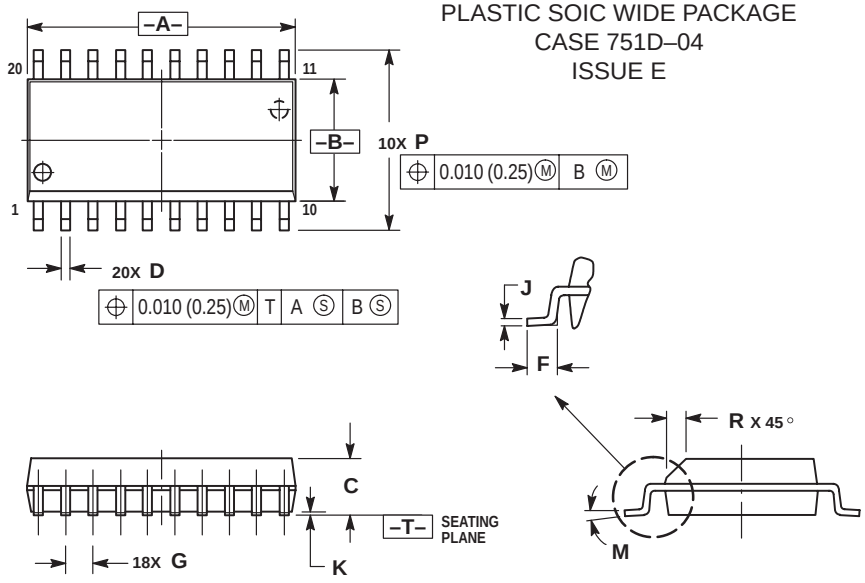
Figure 17. Interfacing to Low Voltage CMOS Outputs

FUNCTION DIAGRAM VHC4351



OUTLINE DIMENSIONS

DW SUFFIX
PLASTIC SOIC WIDE PACKAGE
CASE 751D–04
ISSUE E

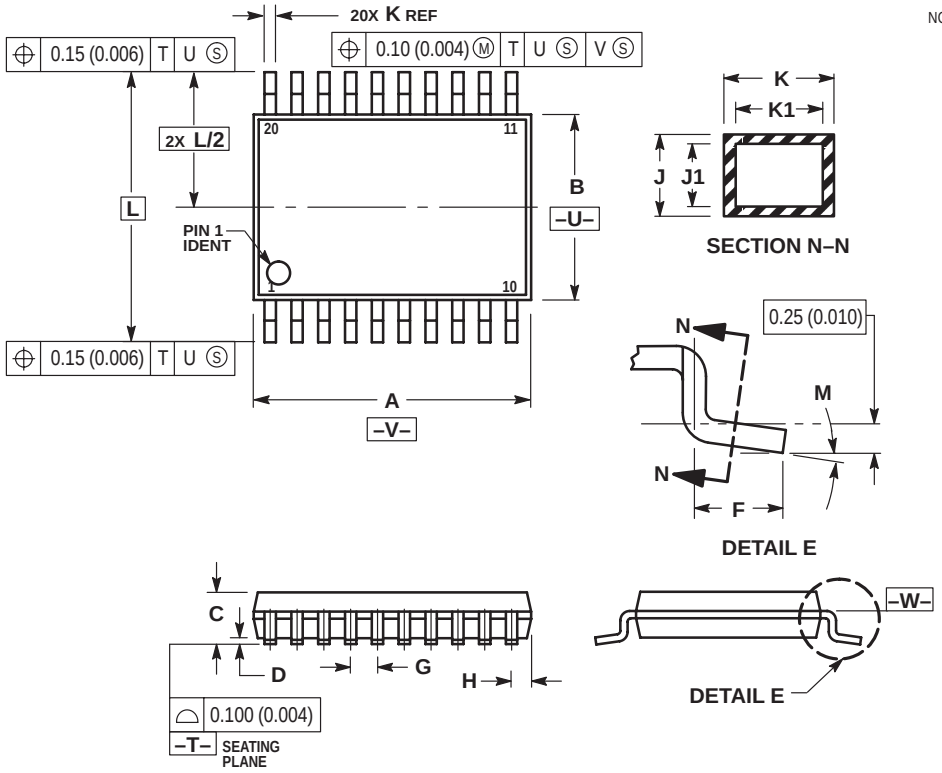


NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.150 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.13 (0.005) TOTAL IN EXCESS OF D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	12.65	12.95	0.499	0.510
B	7.40	7.60	0.292	0.299
C	2.35	2.65	0.093	0.104
D	0.35	0.49	0.014	0.019
F	0.50	0.90	0.020	0.035
G	1.27 BSC		0.050 BSC	
J	0.25	0.32	0.010	0.012
K	0.10	0.25	0.004	0.009
M	0 °	7 °	0 °	7 °
P	10.05	10.55	0.395	0.415
R	0.25	0.75	0.010	0.029

OUTLINE DIMENSIONS

DT SUFFIX
PLASTIC TSSOP PACKAGE
CASE 948E–02
ISSUE A



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE –W–.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	6.40	6.60	0.252	0.260
B	4.30	4.50	0.169	0.177
C	—	1.20	—	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.27	0.37	0.011	0.015
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0°	8°	0°	8°

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